

2STD1360, 2STF1360, 2STN1360

Low voltage fast-switching NPN power transistors

Datasheet - production data

Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast-switching speed

Applications

- Emergency lighting
- LED
- Voltage regulation
- Relay drive

Description

This device is an NPN transistor manufactured using new low voltage planar technology with double metal process. The result is a transistor which boasts exceptionally high gain performance coupled with very low saturation voltage.

The complementary PNP types are the 2STD2360T4, the 2STF2360 and the 2STN2360.

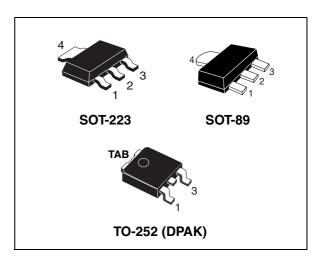


Figure 1. Internal schematic diagram

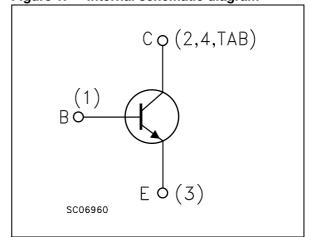


Table 1. Device summary

Order codes	Marking	Packages	Packaging	
2STD1360T4	2STD1360	DPAK	Tape and reel	
2STF1360	1360	SOT-89	Tape and reel	
2STN1360	N1360	SOT-223	Tape and reel	

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This is information on a product in full production.

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

			Value		
Symbol	Parameter	2STD1360	2STF1360	2STN1360	Unit
		DPAK	SOT-89	SOT-223	
V _{CBO}	Collector-base voltage (I _E = 0)		80		V
V _{CEO}	Collector-emitter voltage (I _B = 0)		60		٧
V _{EBO}	Emitter-base voltage $(I_C = 0)$		6		٧
I _C	Collector current		3		Α
I _{CM}	Collector peak current (t _P < 5 ms)	5			Α
I _B	I _B Base current		0.2		
I _{BM}	Base peak current (t _P < 5 ms)	0.4			Α
P _{TOT}	Total dissipation at T _{amb} = 25 °C	15	1.4	1.6	W
T _{stg}	Storage temperature	-65 to 150		°C	
TJ	Max. operating junction temperature 150			°C	

Table 3. Thermal data

Symbol	Parameter		DPAK	SOT-89	SOT-223	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient	Max	8.3	89	78	°C/W

^{1.} Device mounted on a PCB area of 1 cm²

2 Electrical characteristics

 $T_{CASE} = 25$ °C; unless otherwise specified.

Table 4. Electrical characteristics

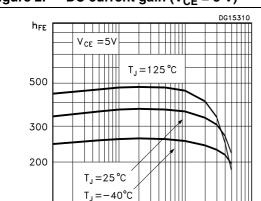
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 80 V			100	nA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 6 V			100	nA
V _{BE(on)}	Base-emitter on voltage	$V_{CE} = 2 V$ $I_{C} = 100 \text{ mA}$	630	650	730	mV
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 2 \text{ A}$ $I_B = 100 \text{ mA}$ $I_C = 3 \text{ A}$ $I_B = 150 \text{ mA}$		130 180	300 500	mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 2 A I _B = 100 mA		0.9	1.2	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 100 \text{ mA}$ $V_{CE} = 2 \text{ V}$ $I_C = 1 \text{ A}$ $V_{CE} = 2 \text{ V}$	80 160		400	
	Resistive load					
t _d	Delay time	$I_C = 3 A$ $V_{CC} = 10 V$		17	20	ns
t _r	Rise time	$I_{B(on)} = -I_{B(off)} = 300 \text{ mA}$		81	100	ns
t _s	Storage time	$V_{BE(off)} = -5 V$		620	720	ns
t _f	Fall time			54	65	ns
f _T	Transition frequency	I _C = 0.1 A V _{CE} = 10 V		130		MHz

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %

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2.1 Typical characteristics (curves)

Figure 2. DC current gain $(V_{CE} = 5 V)$



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Figure 3. DC current gain $(V_{CE} = 2 V)$

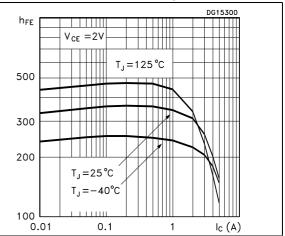
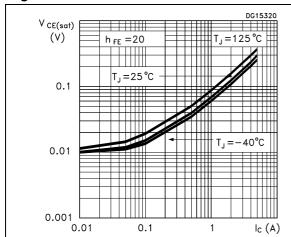


Figure 4. Collector emitter saturation voltage Figure 5. Base emitter saturation voltage

Ic (A)



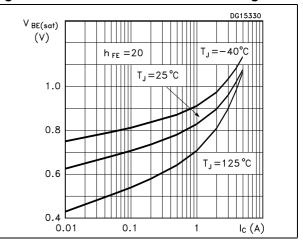


Figure 6. Resistive load switching on

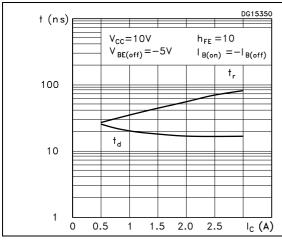
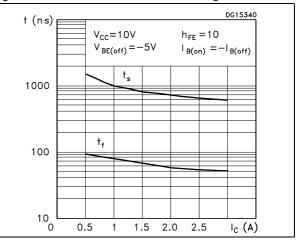


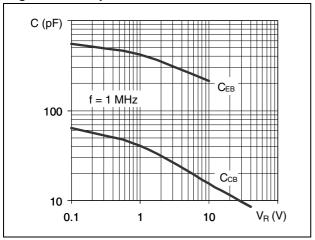
Figure 7. Resistive load switching off



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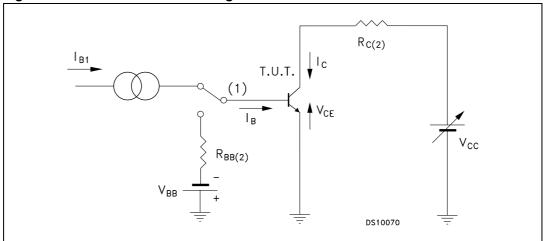
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Figure 8. Capacitance



2.2 Test circuits

Figure 9. Resistive load switching



- 1. Fast electronic switch
- 2. Non-inductive resistor

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

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Table 5. DPAK (TO-252) mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
Α	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
Е	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°

Figure 10. DPAK (TO-252) drawing

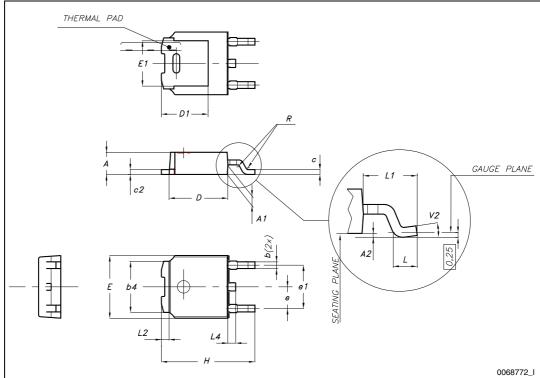
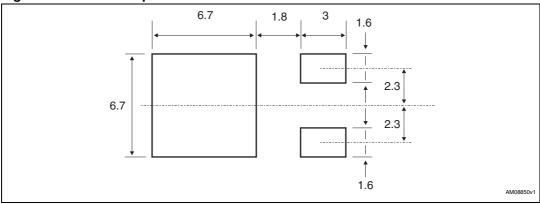


Figure 11. DPAK footprint^(a)



a. All dimensions are in millimeters

Table 6. DPAK (TO-252) tape and reel mechanical data

Таре			Reel		
Dim.	n	nm	n Dim.		nm
Dilli.	Min.	Max.		Min.	Max.
A0	6.8	7	А		330
В0	10.4	10.6	В	1.5	
B1		12.1	С	12.8	13.2
D	1.5	1.6	D	20.2	
D1	1.5		G	16.4	18.4
Е	1.65	1.85	N	50	
F	7.4	7.6	Т		22.4
K0	2.55	2.75			
P0	3.9	4.1		Base qty.	2500
P1	7.9	8.1		Bulk qty.	2500
P2	1.9	2.1			
R	40				
Т	0.25	0.35			
W	15.7	16.3			

Figure 12. Tape for DPAK (TO-252)

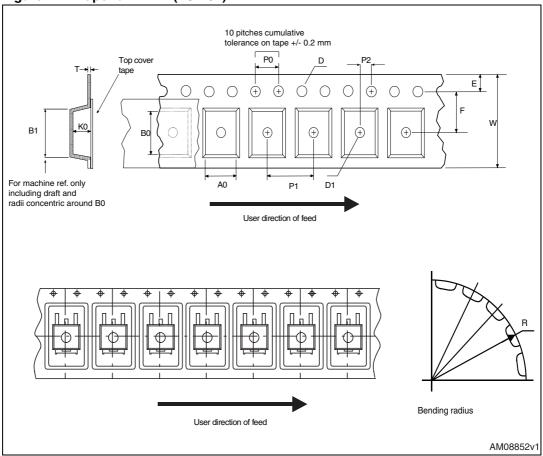


Figure 13. Reel for DPAK (TO-252)

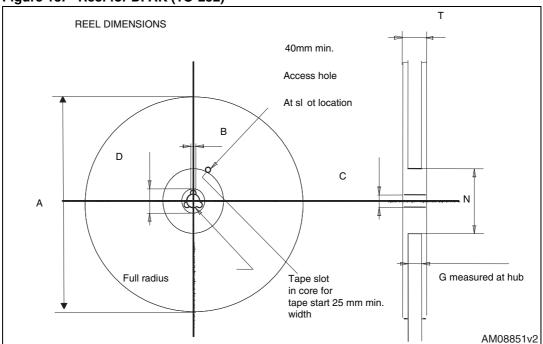
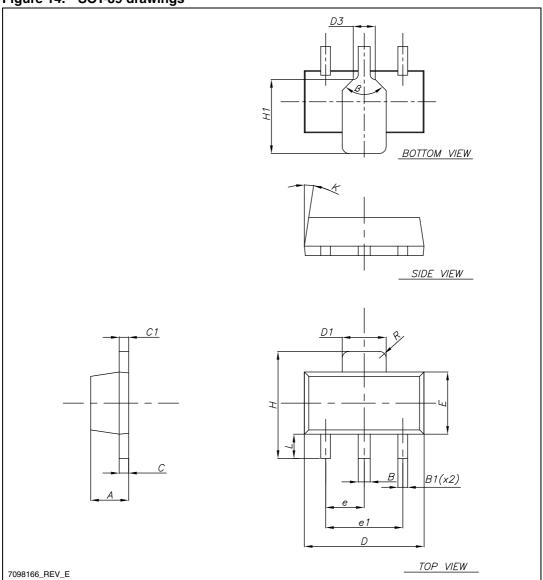


Table 7. SOT-89 mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
А	1.40		1.60
В	0.44		0.56
B1	0.36		0.48
С	0.35		0.44
C1	0.35		0.44
D	4.40		4.60
D1	1.62		1.83
D3		0.90	
Е	2.29		2.60
е	1.42		1.57
e1	2.92		3.07
Н	3.94		4.25
H1	2.70		3.10
K	1°		8°
L	0.89		1.20
R		0.25	
β		90°	

Figure 14. SOT-89 drawings



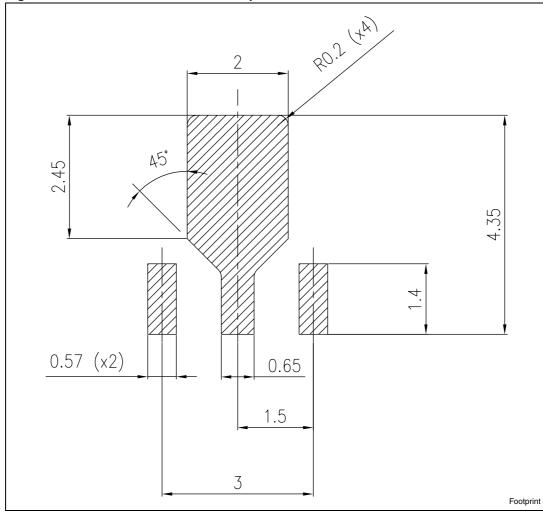
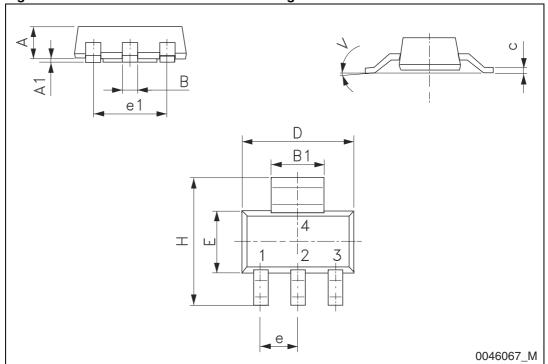


Figure 15. SOT-89 recommended footprint

Table 8. SOT-223 mechanical data

Dim.		mm	
Dilli.	Min.	Тур.	Max.
Α			1.80
A1	0.02		0.1
В	0.60	0.70	0.85
B1	2.90	3.00	3.15
С	0.24	0.26	0.35
D	6.30	6.50	6.70
е		2.30	
e1		4.60	
E	3.30	3.50	3.70
Н	6.70	7.00	7.30
V			10°





4 Revision history

Table 9. Document revision history

Date	Revision	Changes
21-Nov-2005	1	Initial release
09-Oct-2009	2	Added 2STD1360T4 in TO-252 (DPAK) package
13-Aug-2012	3	Modified: marking for DPAK in <i>Table 1</i>

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